

**Amendments to the Specification:**

Please amend the paragraph beginning at p. 3, line 17 with "The capacitors" and ending at p. 3, line 22 with "100 nF/sq. cm." to read as follows:

The capacitors are preferably thin-film parallel-plate type capacitors. Preferred dielectric materials for the capacitors include barium titinate, strontium titinate, and a polymer blended with high dielectric constant particles such as barium titinate, barium strontium titinate, titanium oxide, lead zirconium titinate and tantalum oxide. The capacitance of a typical thin film, parallel-plate capacitor is from about 1 nF/sq. cm. to about 100 nF/sq. cm., in some embodiments from about 2 nF/sq. cm. to about 30 nF/sq. cm. and in other embodiments from about 2 nF/sq. cm. to about 15 nF/sq. cm. In another embodiment the capacitor has a capacitance of at least 30 nF/sq. cm.